Unoccupied surface states on clean and oxygen-covered Cu(110) and Cu(111)

C. T. Chen and N. V. Smith AT&T Bell Laboratories, Murray Hill, New Jersey 07974 (Received 10 April 1989)

The experimentally observed surface states of the adsorbate systems $Cu(110)p(2\times1)O$ and Cu(111)/O₂ can be simulated by a simple model using a planar-averaged surface barrier. The $E(k_{\parallel})$ dispersion curves of the adsorbate case are obtained from those of the clean-surface case by a systematic downward shift in energy which is achieved, in this particular model, by an outward movement of the barrier by ¹—2 a.u.

I. INTRODUCTION

On inspecting the inverse photoemission data of Jacob et al.¹ on Cu(110)p(2×1)O, we were struck by the resemblance of the $E(k_{\parallel})$ dispersion curves for the oxygen-induced electronic states to those generated by a simple model which we had devised for clean surfaces.² In this paper, we explore this resemblance in numerical detail. We find that the $E(k_{\parallel})$ relations for $Cu(110)p(2\times1)O$ can be derived from those for clean Cu(110) by a systematic shift in energy. A similar result is obtained for the adsorption of oxygen on Cu(111). Our findings are relevant to a debate in the literature on the relative importance of planar-averaged electrostatic effects and local-orbital chemical-bonding effects.³

II. SURFACE-STATE MODEL

A. Surface potential barrier

Following our previous work,^{2,4} here we adopt the three-parameter model for a saturated image-potential barrier devised by Jones, Jennings, and Jepsen:

$$
V(z) = \begin{cases} -\frac{1}{2(z - z_0)} (1 - e^{-\lambda(z - z_0)}), & z > z_0 \\ -\frac{U_0}{1 + Ae^{\beta(z - z_0)}}, & z < z_0 \end{cases}
$$
 (1)

The three disposable parameters are z_0 , the distance of the image plane, U_0 , the inner potential, and λ^{-1} , a characteristic distance over which the image potential saturation takes place. The two other parameters A and β are fixed by smooth continuity at $z = z_0$.

The ansatz of Eq. (1) reproduces very well the surface barrier for jellium obtained theoretically by Lang and $Kohn⁶$ (see Ref. 7). It has been used successfully in the analysis of inverse-photoemission data on clean surfaces^{2,4} and of preemergent fine structure in very-lowenergy electron diffraction.^{5,7,8}

B.Adsorbate simulation

Jennings and co-workers^{$7-9$} have pointed out that in classical electrostatics the potential experienced by an electron situated outside a metal with a dielectric layer on its surface may be written

$$
V(z) \sim \frac{-1}{2|z - (z_0 + \delta)|} \left[1 - \frac{2\delta}{(\epsilon + 1)|z - (z_0 + \delta)|}\right], \qquad (2)
$$

where δ is the thickness of the layer and ϵ is its dielectric constant. The principal result is an outward shift of the effective image plane. Following the basic insight, we have tried to simulate the effects of adsorption by simply varying z_0 in Eq. (1). This procedure has previously been found to work quite well in fitting the surface barrier for H chemisorbed on W(001) obtained from first-principles theoretical computations.

It should be recognized that varying z_0 is only one of the possible ways of simulating the adsorbed layer. As z_0 moves away from the solid, the effect is to lower energies of all the surface states. The same effect can be achieved by increasing U_0 , the depth of the inner potential well. Another way would be to introduce, near the outermost atomic layer, a thin sheet of attractive potential. Our derived numerical values for z_0 should therefore not be taken literally. Our concern is to show how the surface states for the adsorbate case can evolve from those of the clean surface.

C. Procedure and terminology

We have used the multiple reflection model¹⁰ in its elementary form¹¹ to generate the surface-state $E(k_{\parallel})$ dispersion relations. The quantization condition is $\Phi_c + \phi_B = 2\pi n$, where ϕ_c and ϕ_B are the phase changes on reflection at the crystal and surface barrier, respectively; ϕ_C is obtained from a two-band nearly-free-electron model, and ϕ_B is obtained for specific values of z_0 by integrating Schrödinger's equation along the z axis.^{2,12}

At $\overline{\Gamma}$, the surface states may be designated as S_n , with S_0 being the usual Shockley state and S_1 , S_2 , etc. being the image state Rydberg series. For gaps centered at the boundary of the surface Brillouin zone, the quantization condition becomes $\phi_C^{\pm}+\phi_B=2\pi n$, and the states may be designated S_n^{\pm} . S_0^- and S_0^+ are odd and even Shockley states; the image states also alternate between odd and even symmetry.

III. NUMERICAL RESULTS AND DISCUSSION

A. Clean Cu(110)

The results of the model for clean Cu(110) are compared with the inverse-photoemission data of Jacob et aL^{13} and the photoemission data of Kevan¹⁴ in Fig. 1. Inverse-photoemission data on this surface have also been reported by Reihl and Frank¹⁵ and by Bartynski et al.¹⁶ In the gap centered at \overline{Y} (associated with the bulk L_2, L_1 gap), three surface states are seen: the odd and even
Shockley states S_0^- and S_0^+ , and the first image state S_1^- . A feature labeled B_1 is also seen in inverse photoemission. This may be associated with the S_0^- state but it overlaps in energy with a bulk direct transition¹³ and so its identification is ambiguous. In the gap centered at \bar{X} (associated with the X_4, X_1 gap), only the S_0^+ state is clearly seen; the S_0^- state, if present, is obscured by the bulk direct transition B_2 .

The theoretical curves of Fig. 1 were generated with a Jones-Jennings-Jepsen barrier having $z_0 = 1.7$ a.u., U_0 =1.06 Ry, and λ =1.01 a.u. The overall match to the data is good, with the exception of the S_0^+ state at \overline{Y} where the theoretical curve lies too high. This discrepancy appears to run consistently through the fcc metals which have been studied⁴ and is not understood. Within the limitations of the multiple reflection model, there appears to be no nonpathological pair of (ϕ_C, ϕ_B) curves which can simultaneously reproduce the $S_0^-, S_0^+,$ and $S_1^$ states of the \bar{Y} gap. Some physical phenomenon beyond the scope of the model, such as contraction of the outermost atomic layer,¹⁷ may be responsible.

FIG. 1. $E(k_{\parallel})$ dispersion of the surface states of clean Cu(110) along the two principal azimuths $\overline{\Gamma} \overline{Y}$ and $\overline{\Gamma} \overline{X}$. The large solid circles are the inverse-photoemission data of Ref. 13. The photoemission data of Ref. 14 below E_F and \overline{Y} are also indicated. Open circles labeled B_1 and B_2 are attributable to bulk direct transitions. Solid curves are the dispersion relations generated by the simple phase accumulation model with an imageplane distance $z_0 = 1.7$ a.u. S_0^- and S_0^+ denote odd and even Shockley states. S_1^- and S_1^+ are the first members of an imagestate Rydberg series converging on the escape threshold (ET) indicated by the dashed curves. The toned area represents the projection of the bulk band structure.

B. Cu(110) $p(2 \times 1)$ O

The results of the model are compared in Fig. 2 with the inverse-photoemission data of Ref. 1 on the adsorbate system Cu(110) $p(2 \times 1)$ O. The symbols A_{1-6} denote the data. For the $\overline{\Gamma} \overline{X}$ azimuth, dashed curves indicate the zone folding (or surface-umklapp effect) associated with the $p(2\times1)$ superlattice. The theoretical curves themselves were obtained by setting $z_0 = 3.6$ a.u. while keeping the values of U_0 and λ the same as for the clean Cu(110) case discussed above. The effect of the larger value of z_0 is to force the $E(k_{\parallel})$ curves downwards in energy. In the phase accumulation model, the surface-state quantization condition is, of course, cyclical in nature; we could easily have arrived at a satisfactory match by a smaller upwards shift of the clean Cu(110) solutions. We choose a downward shift for two reasons. Firstly, it is more physically plausible; the adsorbed oxygen atoms are electronegative, a situation which, if simulated by a thin sheet of attractive potential, would pull the energies down. Secondly, a downward shift is consistent with our treatment of oxygen on Cu(111) presented below.

Near \overline{Y} , we may identify the observed features A_4 , A_3 , and A_1 with the states S_0^+ , S_1^- , and S_1^+ , respectively.
On moving from \overline{Y} to $\overline{\Gamma}(k_{\parallel} = 0)$, the A_1 identification is less clear, although this may be a resolution limitation in which the S_1^- and S_1^+ states are not fully resolved. Near \overline{X} , we may identify the observed features A_5 and A_6 with the states S_0^+ and S_1^- , respectively. Near $\overline{\Gamma}$, we may identify A_1 and A_2 with the states S_0^+ and S_1^- near \bar{X} which have been translated by surface umklapp through a reciprocal-lattice vector of the $p(2\times1)$ superlattice. Thus, all the observed features A_{1-6} are susceptible to interpretation as surface states by a straightforward elaboration of the phase accumulation model.

Our interpretation differs in an important respect from the one offered in Ref. 1. That paper distinguishes be-

FIG. 2. $E(k_{\parallel})$ dispersion of the surface states of the adsorbate system $Cu(110)p(2\times1)O$. Solid circles labeled A_{1-6} are the inverse-photoemission data of Ref. 1. Solid curves labeled S_n^{\pm} are the dispersion curves generated by the phase accumulation model with $z_0 = 3.6$ a.u. The dashed curves near $\overline{\Gamma}$ in the $\overline{\Gamma} \overline{X}$ azimuth are generated from those near \overline{X} by "surface umklapp," i.e., translation through a reciprocal-lattice vector of the $p(2 \times 1)$ superlattice.

tween features derived from the clean Cu(110) states (identified as A_3 , A_4 , and A_5) and those which are not (identified as A_1 , A_2 , and A_6). It is then suggested that one of the latter is the antibonding component of the metal-absorbate covalent bond. This possibility is plausible, but, as our analysis shows, the distinction may not be necessary.

C. $Cu(111)/O₂$

Jacob et al.¹ also report inverse-photoemission data for oxygen adsorbed on Cu(111). One adsorbate-induced feature is seen, and its $E(k_{\parallel})$ dispersion is shown in Fig. 3 as solid circles. We identify this feature as the S_1 image state shifted downwards in energy from its clean surface position. The photoemission¹⁸ and inverse-photoemission¹⁹ data for clean Cu(111) are shown in Fig. 3 for comparison.

Figure 3 also compares the data with the results of our model. The clean Cu(111) and Cu(111)/ O_2 cases are simulated quite well with image distances $z_0 = 2.3$ and 3.7 a.u., respectively. (The values for U_0 and λ are 1.10 Ry and 1.17 a.u. in each case.) Note that adsorbate case could not be derived from a small upwards shift of the clean surface case, reinforcing our choice of downwards shifts in energy as mentioned in Sec. III B.

D. Closing comments

What we have shown in the numerical exercises of this paper is that almost the entire manifold of unoccupied adsorbate-induced surface states on $Cu(110)p(2\times1)O$ and $Cu(111)/O₂$ can be derived from the states of the clean surfaces by a simple modification of the surface barrier. In the interpretive model we have used, the surface states are essentially the standing-wave resonances of the effective cavity between the crystal and surface barrier. Lindgren and Walldén²⁰ have reported similar success in explaining the surface states for layers of alkali metal on various metal substrates. Lenac et al .²¹ have used a similar approach in the study of hydrogen-covered Pd surfaces. These effects may therefore be of some generality. We conclude that such planar-averaged "cavityresonance" possibilities need to be considered before adsorbate-induced features in inverse-photoemission spectra can confidently be assigned to local orbital configurations of a substrate-adsorbate bond.

In the specific case of $Cu(110)p(2\times1)O$, we find that our simple model explains immediately the observed adsorbate-induced features A_3 , A_4 , A_6 and the feature A_1 near \overline{Y} . In our analysis, we are obliged to separate A_1 into two features: an A_1 -near- \overline{Y} feature attributabl to the expected S_1^+ image state, and an A_1 -nearfeature. The latter and also the A_2 feature are explained less directly as the S_0^+ and S_1^- states near \bar{X} translated by

³See, for example, J. K. Norskov, S. Holloway, and N. D. Lang,

FIG. 3. $E(k_{\parallel})$ dispersion relations for clean Cu(111) and the adsorbate system $Cu(111)/O₂$. Open circles are the inversephotoemission data of Ref. 18 on clean Cu(111); the photoemission data of Ref. 17 on clean Cu(111) are shown as the dots near $\overline{\Gamma}$. Solid circles are the inverse-photoemission data of Ref. 1 for $Cu(111)/O₂$. The clean and adsorbate cases have been simulated with the phase accumulation model with image-plane distances z_0 =2.3 and 3.7 a.u. shown, respectively, as the dashed and solid curves.

surface umklapp to the region near $\overline{\Gamma}$. Inspection of Fig. 2 shows that this works well for A_2 , but is less satisfacto-

ry for A_1 -near- $\overline{\Gamma}$.
Angle-resolved photoemission experiments Cu(110) $p(2\times1)$ O by Didio et al.²² reveal an oxygeninduced peak within 1 eV of the top of the Cu d band, which is attributed to the antibonding surface-molecule state in accordance with first-principles calculations on such systems. 23 This work has been refined in some detail by Courths et al , 24 who find that of the three anticipated antibonding states, one is missing. It is suggested that the missing state is either buried within the Cu d-band manifold or is pushed up above E_F to be identified with the A_1 inverse-photoemission feature as advocated in Ref. 1. Tight-binding simulations²⁴ indicate that the latter hypothesis requires a large arbitrary shift of the Cu d-state center of gravity to 3 eV above E_F , as opposed to the 2 eV below E_F which works well for the occupied adsorbate-induced states.

A first-principles calculation would be most welcome to distinguish between the competing possibilities. Such a calculation would need to be done for the (2×1) supercell in order to test for the proposed surface-umklapp effects. It would also need to incorporate the imagepotential asymptotic form for the surface barrier, since this is crucial to the existence of the S_1^- and S_1^+ states and higher members of the image state Rydberg series.

Surf. Sci. 137, 65 (1984); C. Somerton, C. S. McConville, D. P. Woodruff, D. E. Grider, and N. V. Richardson, ibid. 138, 31 (1984); H. S. Luftman, Y. M. Sun, and J. M. White, ibid. 141, 82 (1984); W. Eberhardt, F. M. Hoffmann, R. dePola, D.

Heskett, I. Strathy, E. W. Plummer, and H. R. Moser, Phys. Rev. Lett. 54, 1856 (1985).

- 4N. V. Smith, C. T. Chen, and M. Weinert, Phys. Rev. B 40, 7565 (1989}.
- 5R. O. Jones, P. J. Jennings, and O. Jepsen, Phys. Rev. B 29, 6474 (1984).
- 6N. D. Lang and W. Kohn, Phys. Rev. B 7, 3541 (1973).
- P. J. Jennings. R. O. Jones, and M. Weinert, Phys. Rev. B 37, 6113 (1988).
- 8R. O. Jones and P.J.Jenning, Prog. Surf. Sci. 9, 165 (1988).
- ⁹P. J. Jennings and R. O. Jones, Surf. Sci. 176, 691 (1986).
- ¹⁰P. M. Echenique and J. B. Pendry, J. Phys. C 11, 2065 (1978).
- ¹¹N. V. Smith, Phys. Rev. B 32, 3549 (1985).
- E. G. McRae and M. L. Kane, Surf. Sci. 108, 435 (1981).
- ¹³W. Jacob, V. Dose, U. Kolac, Th. Fauster, and A. Goldmann, Z. Phys. B 63, 459 (1986).
- ¹⁴S. D. Kevan, Phys. Rev. B 28, 4822 (1983).
- ¹⁵B. Reihl and K. H. Frank, Phys. Rev. B 31, 828 (1985).
- ¹⁶R. A. Bartynski, T. Gustafsson, and P. Soven, Phys. Rev. B

3i, 4745 (1985).

- $17F$. Jona and P. M. Marcus, in The Structure of Surfaces II, edited by J. F. van der Veen and M. A. Van Hove (Springer-Verlag, Neve York, 1988), p. 90; D. L. Adams, H. B. Nielsen, and J. N. Andersen, Phys. Scr. T4, 22 (1983).
- ¹⁸S. D. Kevan, Phys. Rev. Lett. 50, 526 (1983).
- ¹⁹S. L. Hulbert, P. D. Johnson, N. G. Stoffel, W. A. Royer, and N. V. Smith, Phys. Rev. B31, 6815 (1985).
- 20 S. A. Lindgren and L. Walldén, Phys. Rev. B 38, 10044 (1988); 38, 3060 (1988); Phys. Rev. Lett. 59, 3003 (1987); 61, 2894 (1988).
- ²¹Z. Lenac, M. Šunjić, H. Conrad, and M. E. Kordesh, Phys. Rev. B36, 9500 (1987).
- $22R$. A. Didio, D. M. Zehner, and E. W. Plummer, J. Vac. Sci. Technol. A 62, 852 (1984).
- ²³A. Liebsch, Phys. Rev. B 17, 1653 (1978).
- ²⁴R. Courths, B. Cord, H. Wern, H. Saalfeld, and S. Hüfner, Solid State Commun. 63, 619 (1987).